Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-045-3146

| Inclosure Material: | |
|--|--|
| Glass | |
| Overall Length: | |
| 0.840 inches | |
| Overall Diameter: | |
| 0.250 inches | |
| Mounting Method: | |
| Press fit | |
| Features Provided: | |
| Hermetically sealed case | |
| Semiconductor Material: | |
| Silicon | |
| Voltage Rating In Volts Per Characteristic: | |
| -15.0 breakdown voltage, dc | |
| Power Rating Per Characteristic: | |
| 500.0 milliwatts total power dissipation | |
| Maximum Operating Tempurature Per Measurement Point: | |
| 75.0 degrees celsius ambient air | |
| Terminal Type And Quantity: | |
| 2 uninsulated wire lead | |
| Shelf Life: | |
| N/a | |
| Unit Of Measure: | |
| | |
| Demilitarization: | |
| No | |
| Fiig: | |
| A110a0 | |